# Technical Information AISWEI Interface

(Based On Modbus Standard Protocol)

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'Modbus' herein refers to industrial standard serial communication protocol.

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## 1 Information on this Document

## Validity

This document is valid for AISWEI inverters.

## **Target Group**

This document is intended for qualified persons. Only persons with appropriate skills are allowed to perform the tasks described in this document.

## Terminology

Information	Explanation
Pn	The rated active power of device
Pm	The instantaneous power when the power control curve reaches the starting point
Sn	The rated apparent power of device

## 2 Safety

#### 2.1 Intended Use

The Modbus interface of the supported devices is designed for industrial use, via RS485 or RS422 protocol to enable remote control of the PV system, remote querying of values, and remote parameter setting.

#### 2.2 Skills of Qualified Persons

The activities described in this document must only be performed by qualified persons. Qualified persons must have the following skills:

- Detailed knowledge of the grid management services
- Knowledge of IP-based network protocols
- · Training in the installation and configuration of IT systems
- Knowledge of the Modbus specifications
- Knowledge of and compliance with this document and all safety information

## 3 AISWEI Modbus Profile

## 3.1 Information on the Assignment Tables

The assignment tables of the AISWEI Modbus profile present the following information:

Information	Explanation
ADR (DEC)	Decimal Modbus address, you need to remove 3x or 4x and subtract 1, then convert to hexadecimal and use it in the communication frame. Such as 31001 (decimal) → 1000 (decimal) → 0x03e8 (hexadecimal)
Description/ number code(s)	Short description of the Modbus registers and the number codes used.
Туре	Type of the data (see Section 3.2).
Unit	Unit of the data.
Gain	Real value = Gain * output value
Access	RO: Read Only RW: Read and Write WO: Write Only

## 3.2 AISWEI Data Types and NaN Values

The following table shows the data types used in the AISWEI Modbus profile and the possible NaN values. The AISWEI data types are listed in the assignment tables in the Type column. They describe the data widths of the assigned values:

Туре	Description	NaN Value
B16	Bit field (16-bit)	0xFFFF
B32	Bit field (32-bit)	0xFFFF FFFF
S16	Signed integer (16-bit)	0x8000
U16	Unsigned integer (16-bit)	0xFFFF
S32	Signed integer (32-bit)	0x8000 0000
U32	Unsigned integer (32-bit)	0xFFFF FFFF
E16	Number code (16-bit)	0xFFFF
String	String type (16-bit, combination of two 8-bit ASCII characters, the high 8-bit is the first ASCII character, and the low 8-bit is the second ASCII character)	0x0000

## 3.3 AISWEI Modbus Profile – Register Overview

In the following table you will find all the measured values and parameters of the AISWEI Modbus Profile.

## **Input Registers**

ADDR(DEC)	Description/number code	Туре	Unit	Gain	Access
31001	Device Type: 1=Single phase / 3=Three pahse	String	-	-	RO
31002	Modbus address: Default as 3	U16	-	-	RO
31003~31018	Serial Number	String	-	=.	RO
31019~31026	Machine type: for example, "ASW3000", please refer to the specific machine in practice	String	-	-	RO
31027	Current grid code: refer to Section 3.5	E16	-	-	RO
31028~31029	Rated Power	U32	W	1.0	RO
31030~31036	Master Software Version	String	-	-	RO
31037~31043	Slave Software Version	String	-	-	RO
31044~31050	Safety Version	String	-	-	RO
31057~31064	Manufacturer's name: for example, "AISWEI", refer to the specific machine	String	-	ı	RO
31065~31072	Brand name: for example, "AISWEI", please refer to the specific machine	String	ı	ı	RO
31301	Grid rated voltage	U16	V	0.1	RO
31302	Grid rated frequency	U16	Hz	0.01	RO
31303~31304	E-Today of inverter	U32	kWh	0.1	RO
31305~31306	E-Total of inverter	U32	kWh	0.1	RO
31307~31308	H-Total	U32	Н	1.0	RO
31309	Device State: 0 = Wait 1 = Normal	E16	-	-	RO

	2 = Fault 4 = Checking				
31310	Connect time	U16	s	1.0	RO
31311	Air temperature	S16	$^{\circ}$ C	0.1	RO
31312	Inverter U phase temperature	S16	$^{\circ}$ C	0.1	RO
31313	Inverter V phase temperature	S16	$^{\circ}$ C	0.1	RO
31314	Inverter W phase temperature	S16	$^{\circ}$ C	0.1	RO
31315	Boost temperature	S16	$^{\circ}$ C	0.1	RO
31316	Bidirectional DC/DC Converter temperature(*)	S16	°C	0.1	RO
31317	Bus voltage	U16	٧	0.1	RO
31319	PV1 voltage	U16	V	0.1	RO
31320	PV1 current	U16	Α	0.01	RO
31321	PV2 voltage	U16	V	0.1	RO
31322	PV2 current	U16	Α	0.01	RO
31323	PV3 voltage(*)	U16	V	0.1	RO
31324	PV3 current(*)	U16	Α	0.01	RO
31325	PV4 voltage(*)	U16	V	0.1	RO
31326	PV4 current(*)	U16	Α	0.01	RO
31327	PV5 voltage(*)	U16	V	0.1	RO
31328	PV5 current(*)	U16	Α	0.01	RO
31329	PV6 voltage(*)	U16	٧	0.1	RO
31330	PV6 current(*)	U16	Α	0.01	RO
31331	PV7 voltage(*)	U16	٧	0.1	RO
31332	PV7 current(*)	U16	Α	0.01	RO
31333	PV8 voltage(*)	U16	V	0.1	RO
31334	PV8 current(*)	U16	Α	0.01	RO
31335	PV9 voltage(*)	U16	V	0.1	RO
31336	PV9 current(*)	U16	Α	0.01	RO
31337	PV10 voltage(*)	U16	٧	0.1	RO
31338	PV10 current(*)	U16	Α	0.01	RO
31339	String 1 current(*)	U16	Α	0.1	RO
31340	String 2 current(*)	U16	Α	0.1	RO

31341	String 3 current(*)	U16	Α	0.1	RO
31342	String 4 current(*)	U16	Α	0.1	RO
31343	String 5 current(*)	U16	Α	0.1	RO
31344	String 6 current(*)	U16	Α	0.1	RO
31345	String 7 current(*)	U16	Α	0.1	RO
31346	String 8 current(*)	U16	Α	0.1	RO
31347	String 9 current(*)	U16	Α	0.1	RO
31348	String 10 current(*)	U16	Α	0.1	RO
31349	String 11 current(*)	U16	Α	0.1	RO
31350	String 12 current(*)	U16	Α	0.1	RO
31351	String 13 current(*)	U16	Α	0.1	RO
31352	String 14 current(*)	U16	Α	0.1	RO
31353	String 15 current(*)	U16	Α	0.1	RO
31354	String 16 current(*)	U16	Α	0.1	RO
31355	String 17 current(*)	U16	Α	0.1	RO
31356	String 18 current(*)	U16	Α	0.1	RO
31357	String 19 current(*)	U16	Α	0.1	RO
31358	String 20 current(*)	U16	Α	0.1	RO
31359	L1 Phase voltage	U16	٧	0.1	RO
31360	L1 Phase current	U16	Α	0.1	RO
31361	L2 Phase voltage(*)	U16	٧	0.1	RO
31362	L2 Phase current(*)	U16	Α	0.1	RO
31363	L3 Phase voltage(*)	U16	٧	0.1	RO
31364	L3 Phase current(*)	U16	Α	0.1	RO
31365	RS Line voltage(*)	U16	V	0.1	RO
31366	RT Line voltage(*)	U16	V	0.1	RO
31367	ST Line voltage(*)	U16	V	0.1	RO
31368	Grid frequency	U16	Hz	0.01	RO
31369~31370	Apparent power	U32	VA	1.0	RO
31371~31372	Active power	S32	W	1.0	RO
31373~31374	Reactive power	S32	Var	1.0	RO
31375	Power factor	S16	-	0.01	RO
31377	Fault state of inverter itself:	E16	-	-	RO

	0 = No internal fault 1 = Internal fault				
31378	Error message:please refer to section 3.4	E16	-	ı	RO
31379	Warning message:please refer to section 3.4	E16	-	ı	RO
31601~31602	PV total power	U32	W	1	RO
31603~31604	PV E-Today	U32	kWh	0.1	RO
31605~31606	PV E-Total	U32	kWh	0.1	RO
31607	Battery communication status: 0x000A=Normal 0x0005=Error	E16	-	-	RO
31608	Battery status: 0 = Not available 1 = Idle 2 = Charging 3 = Discharging 4 = Error	E16	-	-	RO
31609	Battery Error Status 1: bit0 communication data error 0-valid 1-invalid bit1 cell or module voltage is too high 0-valid 1-invalid bit2 Cell or module voltage is too low 0-valid 1-invalid bit3 battery temperature is too high 0-valid 1-invalid bit4 battery temperature is too low 0-valid 1-invalid bit5 discharging current over limit 0-valid 1-invalid bit6 charging current over limit 0-valid 1-invalid bit7 internal communication error 0-valid 1-invalid bit8 Internal cell voltage is un- balance 0-valid 1-invalid bit9 System insulation re- sistance is too low 0-valid 1- invalid bit10 voltage sensor failure 0-	B16	-	-	RO

	valid 1-invalid bit11 temperature sensor failure 0-valid 1-invalid bit12 contactor failure 0-valid 1- invalid bit13 Self-test failure during starting 0-valid 1-invalid bit14 IC self-test failure 0-valid 1-invalid The default value of undefined bit is 1				
31610	Battery Error Status 2: bit0 Self-test failure for battery voltage 0-valid 1-failure bit1 Self-test failure for system voltage 0-valid 1-invalid bit2 Self-test failure for system insulation resistance 0-valid 1- invalid bit3 RTC invalid 0-valid 1- invalid bit4 EEPROM failure 0-valid 1- invalid bit5 Flash failure 0-valid 1- invalid bit6 AFE invalid 0-valid 1- invalid bit7 Chip failure for insulation resistance dectect 0-valid 1- invalid bit9 Chip failure for current sampling 0-valid 1-invalid bit10 HDC failure 0-valid 1- invalid bit11 Daisy chain failure 0-valid 1-invalid bit12 Failure for precharge 0- valid 1-invalid The default value of undefined bit is 1	B16			RO
31613	Battery warning status 1: bit0 Communication data error	B16	1	-	RO

	O velid 4 invelid				
	0-valid 1-invalid bit1 Battery or module voltage is				
	too high 0-valid 1-invalid				
	bit2 Battery or module voltage				
	is too low 0-valid 1-invalid				
	bit3 Battery temperature is too				
	high 0-valid 1-invalid				
	bit4 Battery temperature is too low 0-valid 1-invalid				
	bit5 discharging current over				
	limit 0-valid 1-invalid				
	bit6 charging current over limit 0-valid 1-invalid				
	bit7 Internal communication				
	failure 0-valid 1-invalid				
	bit8 Internal cell voltage is un-				
	balance 0-valid 1-invalid				
	The default value of undefined				
	bit is 1				
31617	Battery voltage	U16	V	0.01	RO
31618	Battery current	S16	Α	0.1	RO
31619~31620	Battery power	S32	w	1	RO
31621	Battery temperature	S16	°C	0.1	RO
31622	Battery SOC	U16	-	0.01	RO
31623	Battery SOH	U16	-	0.01	RO
31624	Battery charging current limit	U16	Α	0.1	RO
31625	Battery discharge current limit	U16	Α	0.1	RO
31626~31627	Battery E-Charge-Today	U32	kWh	0.1	RO
31628~31629	Battery E-Discharge-Today	U32	kWh	0.1	RO
31630~31631	E-Consumption-Today at AC side	U32	kWh	0.1	RO
31632~31633	E-Generation-Today at AC side	U32	kWh	0.1	RO
31634	EPS load voltage	U16	V	0.1	RO
31635	EPS load current	U16	Α	0.1	RO
31636	EPS load frequency	U16	Hz	0.01	RO
31637~31638	EPS load active power	U32	w	1	RO
31639~31640	EPS load reactive power	U32	Var	1	RO

31641~31642	E-Consumption-Today at EPS load side	U32	kWh	0.1	RO
31643~31644	E-Consumption-Total at EPS load side	U32	kWh	0.1	RO
31645	Phase 1 voltage for EPS Load	U16	٧	0.1	RO
31646	Phase 1 cuurent for EPS Load	U16	Α	0.1	RO
31647	Phase 2 voltage for EPS Load	U16	٧	0.1	RO
31648	Phase 2 cuurent for EPS Load	U16	Α	0.1	RO
31649	Phase 3 voltage for EPS Load	U16	V	0.1	RO
31650	Phase 3 cuurent for EPS Load	U16	Α	0.1	RO
31651~31652	Phase 1 active power for EPS Load	U32	w	1	RO
31653~31654	Phase 1 reactive power for EPS Load	S32	Var	1	RO
31655~31656	Phase 2 active power for EPS Load	U32	w	1	RO
31657~31658	Phase 2 reactive power for EPS Load	S32	Var	1	RO
31659~31660	Phase 3 active power for EPS Load	U32	w	1	RO
31661~31662	Phase 3 reactive power for EPS Load	S32	Var	1	RO
31663~31664	Phase 1 active power for Grid	U32	W	1	RO
31665~31666	Phase 1 reactive power for Grid	S32	Var	1	RO
31667~31668	Phase 2 active power for Grid	U32	w	1	RO
31669~31670	Phase 2 reactive power for Grid	S32	Var	1	RO
31671~31672	Phase 3 active power for Grid	U32	w	1	RO
31673~31674	Phase 3 reactive power for Grid	S32	Var	1	RO
31675~31676	Energy charge today for Grid	U32	kWh	0.1	RO
31677~31678	Energy charge total for Grid	U32	kWh	0.1	RO
31679	Battery insulation resistance	U16	kΩ	1	RO
31680	Battery charge/discharge cy- cles	U16	-	1	RO
31681	Environment temperature	U16	%	0.1	RO

## Holding register

ADDR(DEC)	Description/number code	Туре	Unit	Gain	Access
40201	Remote switch command: 0 = POWER OFF 1 = POWER ON 170 = Initialization status	E16	-	-	RW
41001	RTC:Year	U16	-	-	RW
41002	RTC:Month	U16	-	-	RW
41003	RTC:Day	U16	-	-	RW
41004	RTC:Hour	U16	ı	-	RW
41005	RTC:Minute	U16	-	-	RW
41006	RTC:Seconds	U16	-	-	RW
41102	Storage Inverter Switch: 1 - OFF 2 - ON	E16	-	-	RW
41103	Type selection of energy storage machine: 0 - Invalid 1 - Energy storage machine 2 - Grid off inveter 3 - Grid connected inverter 4 - Force charge with City electricity (battery wake-up)	E16	-	-	RW
41104	Run mode: 0 - Invalid 1 - Off 2 - Self generating self use 3 - Backup power	E16	-	-	RW

	supply				
	4 - Customer defined				
41105	Battery manufacturer: 1 - PYLON 2 - DYNESS 3 - BYD 4 - LG 5 - AISWEI	E16	-	-	RW
41108	Smart meter status: 0x000A - Meter Online 0x0005 - Meter Of- fline	E16	1	1	RW
41109	Smart meter adjust- ment flag bit: 0x000A = Start 0x0005 = Stop	E16	ı	-	RW
41110~41111	Set target power value	S32	W	1	RW
41112~41113	Current power value of smart meter	S32	w	1	RW
41114	Anti reverse current flag: 0x000A = ON 0x0005 = OFF	E16	-	-	RW
41115	Battery wake-up (Force charge) sign: 0x000A = ON 0x0005 = OFF 0xFFFF =Not triggered	E16	-	-	RW
41116	UPS function:  0 = Enable EPS function  1 = Enable UPS function	U16	-	-	RW
41151	Commbox and cloud communication status: 0x000A = Cloud Online 0x0005 = Cloud Of-	E16	-	-	RW

	1				
	fline 0x00AF = Network not configured				
41152	Charge discharge flag bit: 1 - Stop 2 - Charging 3 - Discharge	E16	-	-	RW
41153	Charge and discharge power command: ' – '- charging power ' + '- discharge power	S16	W	1	RW
41154	Charging SOC upper limit	U16	%	0.01	RW
41155	Discharge SOC lower limit	U16	%	0.01	RW
41156	Obtaining power ratio of power grid	U16	%	0.01	RW
44001	Active power control function: 0 = Disable 1 = Enable	E16	-	-	RW
44002	EEG control function: 0 = Disable 1 = Enable	E16	-	ı	RW
44003	Slope load function: 0 = Disable 1 = Enable	E16	ı	ı	RW
44004	Overvoltage reduce power function: 0 = Disable 1 = Enable	E16	-	1	RW
44005	Overfrequency reduce power function: 0 = Disable 1 = Enable	E16	-	-	RW
44006	Reactive power control fucntion: 0 = Disable 1 = Enable	E16	-	-	RW

44007	LVRT Function: 0 = Disable 1 = Enable	E16	1	ı	RW
44008	HVRT Function: 0 = Disable 1 = Enable	E16	-	-	RW
44009	10 Minutes Average Overvoltage protect fucntion 0 = Disable 1 = Enable	E16	-	-	RW
44010	Islanding protect func- tion: 0 = Disable 1 = Enable	E16	-	ı	RW
44012	PE connnection check function: 0 = Disable 1 = Enable	E16	-	ı	RW
44014	AFCI function: 0 = Disable 1 = Enable	E16	-	-	RW
44015	PV string current monitoring function: 0 = Disable 1 = Enable	E16	ı	ı	RW
44017	Overload function: 0 = Disable 1 = Enable	E16	1	-	RW
44019	SPD detection function: 0 = Disable 1 = Enable	E16	-	-	RW
44020	Low voltage increase power function: 0 = Disable 1 = Enable	E16	-	-	RW
44021	Low frequency increase power function:  0 = Disable	E16	_	-	RW

	Г	l			
	1 = Enable				
44023	Primary low frequency function(*): 0 = Disable 1 = Enable	E16	-	-	RW
44024	Communication loss detection function(*): 0 = Disable 1 = Enable	E16	-	1	RW
44025	Shadow MPPT func- tion: 0 = Disable 1 = Enable	E16	-	1	RW
44026	External input signal function: 0 = Disable 1 = Enable	E16	-	-	RW
44027	Sunspec write function: 0 = Disable 1 = Enable	E16	ı	ı	RW
45201	Grid code: please refer to section 3.5	E16	-	-	RW
45202	Overvoltage protection value of the first grid connection	U16	٧	0.1	RW
45203	Overvoltage protection value of the first grid connection	U16	V	0.1	RW
45204	Overvoltage protection value of the first grid connection	U16	Hz	0.01	RW
45205	Underfrequency pro- tection value for first grid connection	U16	Hz	0.01	RW
45206	Grid Voltage High Limit3	U16	٧	0.1	RW
45207~45208	Grid Voltage High Limit Time3	U32	ms	1.0	RW
45209	Grid Voltage High	U16	V	0.1	RW

	Limit2				
45210~45211	Grid Voltage High Limit Time2	U32	ms	1.0	RW
45212	Grid Voltage High Limit1	U16	٧	0.1	RW
45213~45214	Grid Voltage High Limit Time1	U32	ms	1.0	RW
45215	Grid Voltage Low Limit3	U16	٧	0.1	RW
45216~45217	Grid Voltage Low Limit Time3	U32	ms	1.0	RW
45218	Grid Voltage Low Limit2	U16	V	0.1	RW
45219~45220	Grid Voltage Low Limit Time2	U32	ms	1.0	RW
45221	Grid Voltage Low Limit1	U16	V	0.1	RW
45222~45223	Grid Voltage Low Limit Time1	U32	ms	1.0	RW
45224	10 Minutes Average Overvoltage Threshold	U16	V	0.1	RW
45225	10 Minutes Average Overvoltage Portect Time	U16	ms	1.0	RW
45226	Overvoltage recover value	U16	٧	0.1	RW
45227	Undervoltage recover value	U16	٧	0.1	RW
45228	Grid Frequency High Limit3	U16	Hz	0.01	RW
45229~45230	Grid Frequency High Limit Time3	U32	ms	1.0	RW
45231	Grid Frequency High Limit2	U16	Hz	0.01	RW
45232~45233	Grid Frequency High Limit Time2	U32	ms	1.0	RW
45234	Grid Frequency High Limit1	U16	Hz	0.01	RW

45235~45236	Grid Frequency High Limit Time1	U32	ms	1.0	RW
45237	Grid Frequency Low Limit3	U16	Hz	0.01	RW
45238~45239	Grid Frequency Low Limit Time3	U32	ms	1.0	RW
45240	Grid Frequency Low Limit2	U16	Hz	0.01	RW
45241~45242	Grid Frequency Low Limit Time2	U32	ms	1.0	RW
45243	Grid Frequency Low Limit1	U16	Hz	0.01	RW
45244~45245	Grid Frequency Low Limit Time1	U32	ms	1.0	RW
45246	Vary rate of Frequecny protect value	U16	Hz/s	0.01	RW
45247~45248	Vary rate of Frequecny protect time	U32	ms	1.0	RW
45249	Overfrequency recover value	U16	Hz	0.01	RW
45250	Underfrequency re- cover value	U16	Hz	0.01	RW
45251	Time of first connection to grid	U16	S	1.0	RW
45252	Time of re-connection to grid	U16	S	1.0	RW
45253	ISO protect threshold	U16	kΩ	1.0	RW
45254	DCI protect threshold	U16	mA	1.0	RW
45255	DCI protect time	U16	ms	1.0	RW
45401	Load rate of first con- nection to grid	U16	%Pn/min	1.0	RW
45402	Load rate of re- connection to grid	U16	%Pn/min	1.0	RW
45403	Active Power Set	U16	%Pn	0.01	RW
45404	Increase rate of active power	U16	%Pn/min	0.01	RW
45405	Decrease rate of active	U16	%Pn/min	0.01	RW
	· · · · · · · · · · · · · · · · · · ·	· ·			

	power				
45408	Over frequency reduce power mode:  0 = None  1 = Fixed reduction ratio, non - hysteresis  2 = Fixed reduction ratio, hysteresis  3 = Not fixed reduction ratio, non - hysteresis  4 = Not fixed reduction ratio, hysteresis  5 = Three points over frequency reduce power, non - hysteresis  6 = Three points over frequency reduce power, hysteresis  7 = Energy storage Italy over frequency reduce power, non - hysteresis  8 = Energy storage Italy over frequency reduce power, hysteresis	E16	-	-	RW
45409	Over frequency reduce power: Start frequency	U16	Hz	0.01	RW
45410	Over frequency reduce power: Stop frequecny	U16	Hz	0.01	RW
45411	Over frequency reduce power: Back frequency	U16	Hz	0.01	RW
45412	The reduce ratio of over frequency reduce power	U16	%Pnor%Pm	0.01	RW
45413	Over frequency reduce power delay time	U16	s	0.1	RW

45414	Over frequency reduce power:recover power delay time	U16	s	0.1	RW
45416	Speed of Over frequency recover to Pn	U16	%Pn/min	0.01	RW
45417	Over frequency reduce power(*):  O power frequency point	U16	Hz	0.01	RW
45419	Over voltage reduce power mode: 0 = None 1 = Not fixed reduction ratio, non – hysteresis 2 = Not fixed reduction ratio, hysteresis 3 = Fixed reduction ratio, non – hysteresis 4 = Fixed reduction ratio, hysteresis 5 = Taiwan's autonomous power regulation 6 = Trina Solar customization mode	E16	-	-	RW
45420	Over voltage reduce power: Start voltage	U16	%Un	0.01	RW
45422	Over voltage reduce power: Stop voltage	U16	%Un	0.01	RW
45424	Over voltage reduce power: Back voltage	U16	%Un	0.01	RW
45426	The reduce ratio of over voltage reduce power	U16	%Pnor%Pm	0.01	RW
45427	Over voltage reduce power delay time	U16	S	0.1	RW
45428	Over voltage recover power delay time	U16	s	0.1	RW
45429	Speed of Over voltage	U16	%Pn/min	0.01	RW

	recover to Pn				
45432	Under frequency increase power mode:  0 = None  1 = Fixed reduction ratio, non - hysteresis  2 = Fixed reduction ratio, hysteresis  3 = Not fixed reduction ratio, non - hysteresis  4 = Not fixed reduction ratio, hysteresis  5 = Three points under frequency increase power, non - hysteresis  6 = Three points under frequency increase power, hysteresis  7 = Energy storage Italy under frequency increase power, non - hysteresis  8 = Energy storage Italy under frequency increase power, hysteresis	E16	-	ı	RW
45433	Under frequency in- crease power: Start frequency	U16	Hz	0.01	RW
45434	Under frequency in- crease power: Stop frequecny	U16	Hz	0.01	RW
45435	Under frequency in- crease power: Back frequency	U16	Hz	0.01	RW
45436	The increase ratio of under frequency increase power	U16	%Pnor%Pm	0.01	RW
45437	Under frequency in- crease power delay time	U16	S	0.1	RW

45438	Under frequency re- cover power delay	U16	s	0.1	RW
	time				
45440	Speed of Under frequency recover to Pn	U16	%Pn/min	0.01	RW
45441	Under frequency in- crease power 0 power frequency point	U16	Hz	0.01	RW
45443	Under voltage increase power mode: 0 = None 1 = Fixed increase ratio, non - hysteresis 2 = Fixed increase ratio, hysteresis 3 = Not fixed increase ratio, non - hysteresis 4 = Not fixed increase ratio, hysteresis	E16	-	ı	RW
45444	Under voltage increase power: Start voltage	U16	%Un	0.01	RW
45445	Under voltage increase power: Stop voltage	U16	%Un	0.01	RW
45446	Under voltage increase power: Back voltage	U16	%Un	0.01	RW
45447	The increase ratio of under voltage increase power	U16	%Pnor%Pm	0.01	RW
45448	Under voltage increase power delay time	U16	s	0.1	RW
45449	Under voltage increase power delay time	U16	S	0.1	RW
45450	Speed of under voltage recover to Pn	U16	%Pn/min	0.01	RW
45451	Pav(*)	S16	%Pn	0.01	RW
45452	DRMs Pval(*)	U16	%Pn	0.01	RW
45501	Reactive power con-	E16	-	-	RW

	trol mode: 0 = None 1 = Fixed power factor 2 = cos φ(P) curve 3 = Fixed Q value 4 = Fixed Q value of AU DRMs 5 = Linear Q(U) curve 6 = Hysteresis Q(U) curve 7 = Taiwan's autonomous control and regulation				
45502	Time constant of reactive power curve	U16	s	1.0	RW
45503	Power factor	S16	-	0.0001	RW
45504	$\cos \varphi(P)$ curve: Active power of the first point	U16	%Pn	0.01	RW
45505	$\cos \varphi(P)$ curve: $\cos \varphi$ of the first point	S16	-	0.0001	RW
45506	cos φ(P) curve: Active power of the second point	U16	%Pn	0.01	RW
45507	$\begin{array}{c} cos \ \phi(P) \ curve: \\ cos \ \phi \ of \ the \ second \\ point \end{array}$	S16	ı	0.0001	RW
45508	$\begin{array}{c} cos \ \phi(P) \ curve: \\ Active \ power \ of \ the \\ third \ point \end{array}$	U16	%Pn	0.01	RW
45509	$\cos \varphi(P)$ curve: $\cos \varphi$ of the third point	S16	-	0.0001	RW
45510	$\cos \varphi(P)$ curve: Active power of the fourth point	U16	%Pn	0.01	RW
45511	$\cos \varphi(P)$ curve: $\cos \varphi$ of the fourth point	S16	-	0.0001	RW
45512	Lock in voltage (for cos φ(P) curve )	U16	%Un	0.01	RW

	1				
45513	Lock out voltage (for cos φ(P) curve)	U16	%Un	0.01	RW
45516	Q Set Value	S16	%Sn	0.01	RW
45518	Q(U) curve: U of the first point	U16	%Un	0.01	RW
45519	Q(U) curve: Q of the first point	S16	%Sn	0.01	RW
45520	Q(U) curve: U of the second point	U16	%Un	0.01	RW
45521	Q(U) curve: Q of the second point	S16	%Sn	0.01	RW
45522	Q(U) curve: U of the third point	U16	%Un	0.01	RW
45523	Q(U) curve: Q of the third point	S16	%Sn	0.01	RW
45524	Q(U) curve: U of the fourth point	U16	%Un	0.01	RW
45525	Q(U) curve: Q of the fourth point	S16	%Sn	0.01	RW
45526	Lock in power (for Q(U) curve)	U16	%Pn	0.01	RW
45527	Lock outpower (for Q(U) curve)	U16	%Pn	0.01	RW
45601	LVRT reactive current calculation mode: 0 = None 1 = GB/T 19964 2 = BDEW	E16	-	ı	RW
45602	LVRT three phase fault reactive current limit	U16	%ln	0.01	RW
45603	LVRT single/double phase fault reactive current limit	U16	%ln	0.01	RW
45604	LVRT fault detection voltage type: 0 = Phase voltage 1 = Line voltage 2 = Positive sequence voltage	E16	-	-	RW

Threshold of insensi- tive area of positive sequence voltage jump	U16	%Un	0.1	RW
LVRT Trigger voltage	U16	%Un	0.01	RW
K-factor of positive sequence reactive current	U16	-	0.01	RW
reactive power maintenance after LVRT voltage recovery	U16	ms	1	RW
LVRT active power limit mode: 0 = Active power first 1 = Active power re- duced to below 10% In 2 = Unlimited active power	E16	1	1	RW
HVRT reactive current calculation mode: 0 = None 1 = GB/T 19964 2 = BDEW	E16	1	1	RW
HVRT three phase fault reactive current limit	U16	%In	0.01	RW
HVRT single/double phase fault reactive current limit	U16	%ln	0.01	RW
HVRT fault detection voltage type: 0 = Phase voltage 1 = Line voltage 2 = Positive sequence voltage	E16	-	-	RW
Threshold of insensi- tive area of negative sequence voltage jump	U16	%Un	0.1	RW
HVRT Trigger voltage	U16	%Un	0.01	RW
K-factor of negative sequence reactive	U16	-	0.01	RW
	tive area of positive sequence voltage jump LVRT Trigger voltage K-factor of positive sequence reactive current reactive power maintenance after LVRT voltage recovery LVRT active power limit mode:  0 = Active power first 1 = Active power reduced to below 10% In 2 = Unlimited active power HVRT reactive current calculation mode:  0 = None 1 = GB/T 19964 2 = BDEW HVRT three phase fault reactive current limit HVRT single/double phase fault reactive current limit HVRT fault detection voltage type:  0 = Phase voltage 1 = Line voltage 2 = Positive sequence voltage Threshold of insensitive area of negative sequence voltage K-factor of negative	tive area of positive sequence voltage jump  LVRT Trigger voltage  K-factor of positive sequence reactive current  reactive power maintenance after LVRT voltage recovery  LVRT active power first 1 = Active power reduced to below 10% In 2 = Unlimited active power  HVRT reactive current calculation mode:  0 = None  1 = GB/T 19964  2 = BDEW  HVRT three phase fault reactive current limit  HVRT single/double phase fault reactive current limit  HVRT fault detection voltage type:  0 = Phase voltage  1 = Line voltage  2 = Positive sequence voltage  Threshold of insensitive area of negative sequence voltage  HVRT Trigger voltage  HVRT Trigger voltage  HVRT Trigger voltage  U16  K-factor of negative  I116	tive area of positive sequence voltage jump  LVRT Trigger voltage U16 %Un  K-factor of positive sequence reactive current  reactive power maintenance after LVRT voltage recovery  LVRT active power first 1 = Active power reduced to below 10% In 2 = Unlimited active power  HVRT reactive current calculation mode: 0 = None 1 = GB/T 19964 2 = BDEW  HVRT three phase fault reactive current limit  HVRT single/double phase fault reactive current limit  HVRT fault detection voltage type: 0 = Phase voltage 1 = Line voltage 2 = Positive sequence voltage	tive area of positive sequence voltage jump  LVRT Trigger voltage  K-factor of positive sequence reactive current reactive power maintenance after LVRT voltage recovery  LVRT active power first 1 = Active power reduced to below 10% In 2 = Unlimited active power HVRT reactive current calculation mode: 0 = None 1 = GB/T 19964 2 = BDEW  HVRT three phase fault reactive current limit HVRT single/double phase fault reactive current limit HVRT fault detection voltage type: 0 = Phase voltage 1 = Line voltage 2 = Positive sequence voltage Threshold of insensitive area of negative sequence voltage HVRT Trigger voltage HVRT Trigger voltage U16 %Un 0.01  K-factor of negative U16 %Un 0.01

	current				
45617	reactive power maintenance after HVRT voltage recov- ery	U16	ms	1	RW
45618	HVRT active power limit mode: 0 = Active power first 1 = Active power re- duced to below 10% In 2 = Unlimited active power	E16	-	-	RW
45619	Zero current threshold	U16	%Un	0.01	RW
46520	AFCI self-test status: 0 = self-test failed 1 = self-test successful	E16	-	-	RO
46521	AFCI detection sensitivity settings: 0 = high detection accuracy 1 = low detection accuracy	E16	-	-	RW
46522	AFCI fault reset method selection: 0 = automatic mode 1 = manual mode	E16	-	-	RW
46523	Reset faults manually: 0 = no need 1 = Manual clear fault (active in arc fault and manual reset mode)	E16	-	-	RW

<sup>(\*) -----</sup> Supported on some models

31601~31681, 41102~41156 Special for storage inverter

## 3.4 Warning and Error Codes

Warning Code	Description
0	No warning
30	Recover from warning
150	SPD Damaged
156	Internal fan warning
157	External fan warning
163	String current abnormal
165	Ground connect warning
166	CPU self-test Register abnornal
167	CPU self-test RAM abnornal
168	CPU self-test ROM abnornal
174	Low Air Temprature
175	Battery Soc Low
176	Battery Fault Status
177	Battery Communication DisConnect
178	EPS Output Over
179	Combox and Cloud Disconnect
180	PV string inverse

Error Code	Description
1	Communication Fails between M-S
3	Relay check Fail
4	DC Injection High
5	The result of Auto Test Function is fail
6	DC bus is too high
8	AC HCT Failure
9	GFCI Device Failure
10	Device fault
32	ROCOF Fault
33	Fac Faulure :Fac Out of Range
34	AC Voltage Out of Range
35	Utility Loss
36	GFCI Failure
37	PV Over Voltage
38	Isolation Fault
40	Over temperature in Inverter
41	Consistent Fault :Vac differs for M-S
42	Consistent Fault :Fac differs for M-S
43	Consistent Fault :Groud I differs for M-S
44	Consistent Fault :DC inj. Differs for M-S
45	Consistent Fault :Fac,Vac differs for M-S
46	High DC bus
47	Consistent Fault
48	Average volt of ten minutes Fault
49	PV1 lightning arrester fault
50	PV2 lightning arrester fault
51	Fuse failure
52	Neutral line loss fault
53	Insulation impedance test: before enabling the constant current source, the sampling value of insulation imped-

	ance measurement voltage is greater than 300mV
54	Insulation impedance detection: after enabling constant current source, the sampling value of insulation imped-
55	ance measurement voltage is out of range (1.37V±20%)  Insulation impedance detection: N-PE relay switches, and the instantaneous value of insulation impedance measurement voltage is less than 40mV
56	GFCI protect fault:30mA level
57	GFCI protect fault:60mA level
58	GFCI protect fault:150mA level
59	PV1 string current is abnormal
60	PV2 string current is abnormal
61	DRMS Communication Fails(S9 Open)
62	DRMS order disconnection device(S0 Close)
63	L-PE short-circuit protection error
64	PV input mode error
65	PE connection Fault
66	PV1 reverse connection fault
67	PV2 reverse connection fault
68	PV3 reverse connection fault
69	External input failure
70	AFCI self-test failure (including self-test circuit and CAN circuit failure)
71	AFCI failure (PV1-10)
72	Parallel 485 communication fault
73	Parallel CAN communication fault

## 3.5 Grid Codes

Grid Code	Description
8	GR PPC
35	NB/T32004:2018
47	AU AS 4777.2 : 2015
48	NZ AS 4777.2 : 2015
49	ENGG-50Hz
50	ENGG-60Hz
51	TOR Erzeuger Typ A V1.1
59	CNS15382:2018
64	EN 50549-1
65	NL EN50549-1:2019
66	BR NBR 16149:2013
67	VDE0126-1-1/A1/VFR
68	IEC 61727 50Hz
69	C10/11:2019
70	VDE-AR-N4105:2018
71	IEC 61727 60Hz
72	G98/1
73	G99/1
74	AU AS/NZS4777.2:2020 A
75	AU AS/NZS4777.2:2020 B
76	AU AS/NZS4777.2:2020 C
77	NZ AS/NZS4777.2:2020
78	IL \$14777.3
79	KR KS C 8565:2020
80	ES UNE206007-1
81	CY EN50549-1
82	CS PPDS A1
83	PL EN50549-1

84       CEI 0-21:2019         85       DK EN50549-1         86       CH NA/EEA-NE7         87       SE EIFS:2018         88       FI EN50549-1         89       RO Order208         90       SI EN50549-1         91       LV EN50549-1         92       VDE0126/VFR2019 IS (50Hz)         93       VDE0126/VFR2019 IS (60Hz)         94       ZA NRS 097-2-1:2017         95       BR PORTARIA No.140         96       NTS 631 Type A         97       NTS 631 Type B         98       NO EN50549-1         99       VDE-AR-N 4110         100       EN 50549-2         101       DEWA:2016         102       DK1 EN50549-1         103       ZA RPPs		
86       CH NA/EEA-NE7         87       SE EIFS:2018         88       FI EN50549-1         89       RO Order208         90       SI EN50549-1         91       LV EN50549-1         92       VDE0126/VFR2019 IS (50Hz)         93       VDE0126/VFR2019 IS (60Hz)         94       ZA NRS 097-2-1:2017         95       BR PORTARIA No.140         96       NTS 631 Type A         97       NTS 631 Type B         98       NO EN50549-1         99       VDE-AR-N 4110         100       EN 50549-2         101       DEWA:2016         102       DK1 EN50549-1	84	CEI 0-21:2019
87 SE EIFS:2018 88 FI EN50549-1 89 RO Order208 90 SI EN50549-1 91 LV EN50549-1 92 VDE0126/VFR2019 IS (50Hz) 93 VDE0126/VFR2019 IS (60Hz) 94 ZA NRS 097-2-1:2017 95 BR PORTARIA No.140 96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	85	DK EN50549-1
88 FI EN50549-1 89 RO Order208 90 SI EN50549-1 91 LV EN50549-1 92 VDE0126/VFR2019 IS (50Hz) 93 VDE0126/VFR2019 IS (60Hz) 94 ZA NRS 097-2-1:2017 95 BR PORTARIA No.140 96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	86	CH NA/EEA-NE7
RO Order208  90 SI EN50549-1  91 LV EN50549-1  92 VDE0126/VFR2019 IS (50Hz)  93 VDE0126/VFR2019 IS (60Hz)  94 ZA NRS 097-2-1:2017  95 BR PORTARIA No.140  96 NTS 631 Type A  97 NTS 631 Type B  98 NO EN50549-1  99 VDE-AR-N 4110  100 EN 50549-2  101 DEWA:2016  102 DK1 EN50549-1	87	SE EIFS:2018
90 SI EN50549-1 91 LV EN50549-1 92 VDE0126/VFR2019 IS (50Hz) 93 VDE0126/VFR2019 IS (60Hz) 94 ZA NRS 097-2-1:2017 95 BR PORTARIA No.140 96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	88	FI EN50549-1
91	89	RO Order208
92 VDE0126/VFR2019 IS (50Hz) 93 VDE0126/VFR2019 IS (60Hz) 94 ZA NRS 097-2-1:2017 95 BR PORTARIA No.140 96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	90	SI EN50549-1
93 VDE0126/VFR2019 IS (60Hz) 94 ZA NRS 097-2-1:2017 95 BR PORTARIA No.140 96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	91	LV EN50549-1
94       ZA NRS 097-2-1:2017         95       BR PORTARIA No.140         96       NTS 631 Type A         97       NTS 631 Type B         98       NO EN50549-1         99       VDE-AR-N 4110         100       EN 50549-2         101       DEWA:2016         102       DK1 EN50549-1	92	VDE0126/VFR2019 IS (50Hz)
95 BR PORTARIA No.140 96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	93	VDE0126/VFR2019 IS (60Hz)
96 NTS 631 Type A 97 NTS 631 Type B 98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	94	ZA NRS 097-2-1:2017
97 NTS 631 Type B  98 NO EN50549-1  99 VDE-AR-N 4110  100 EN 50549-2  101 DEWA:2016  102 DK1 EN50549-1	95	BR PORTARIA No.140
98 NO EN50549-1 99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	96	NTS 631 Type A
99 VDE-AR-N 4110 100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	97	NTS 631 Type B
100 EN 50549-2 101 DEWA:2016 102 DK1 EN50549-1	98	NO EN50549-1
101 DEWA:2016 102 DK1 EN50549-1	99	VDE-AR-N 4110
102 DK1 EN50549-1	100	EN 50549-2
1011	101	DEWA:2016
103 ZA RPPs	102	DK1 EN50549-1
	103	ZA RPPs

#### 3.6 Frame format

MODBUS protocol format: RTU format. Each communication data unit is composed of 1 bit starting bit, 8 bit data bit and 1 bit stopping bit, no parity.

#### MODBUS function codes:

- Read Holding Register (0x03)
- Read Input Register (0x04)
- Write Holding Single Register (0x06)
- Write Holding Multiple Registers (0x10)
- Write Holding Multiple Registers (0x10) for broadcast

## 3.6.1 Read Holding Register (Function Code: 0x03)

#### Request:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Register length	2 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

#### Response:

Device ID	1 Byte
Function code	1 Byte
Byte count	1 Byte
Data	N × 1 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

Device ID	1 Byte
Function code + 0x80	1 Byte
Exception code	1 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

## 3.6.2 Read Input Register (Function Code: 0x04)

## Request:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Register length	2 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

## Response:

Device ID	1 Byte
Function code	1 Byte
Byte count	1 Byte
Data	N × 1 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

Device ID	1 Byte
Function code + 0x80	1 Byte
Exception code	1 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

## 3.6.3 Write Single Holding Register (Function Code: 0x06)

## Request:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Data	2 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

#### Response:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Data	2 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

Device ID	1 Byte
Function code + 0x80	1 Byte
Exception code	1 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

## 3.6.4 Write Multiple Holding Registers (Function Code: 0x10)

## Request:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Register length	2 Byte
Data length	1 Byte
Data	N × 1Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

#### Response:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Register length	2 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

Device ID	1 Byte
Function code + 0x80	1 Byte
Exception code	1 Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

## 3.6.5 Write Multiple Holding Registers (Function Code: 0x10) for broadcast

#### Request:

Device ID	1 Byte
Function code	1 Byte
Register Address(Hi)	1 Byte
Register Address(Lo)	1 Byte
Register length	2 Byte
Data length	1 Byte
Data	N × 1Byte
CRC(Lo)	1 Byte
CRC(Hi)	1 Byte

Response: none

## 3.6.6 Exception Codes

0x01 Illegal function 0x02 Illegal address 0x03 Illegal data

0x04 Slave device failure

## 4 Contact

If you experience any technical problems with our products, please contact the AISWEI Service Hotline to provide you with the necessary assistance:

AISWEI Technology Co., Ltd. Room 905B, 757 Mengzi Road, Huangpu District 200023 Shanghai(P.R. China)